CPC COOPERATIVE PATENT CLASSIFICATION

H ELECTRICITY

(NOTE omitted)

H01 ELECTRIC ELEMENTS

(NOTES omitted)

H01G CAPACITORS; CAPACITORS, RECTIFIERS, DETECTORS, SWITCHING DEVICES, LIGHT-SENSITIVE OR TEMPERATURE-SENSITIVE DEVICES OF THE ELECTROLYTIC TYPE (selection of specified materials as dielectric H01B 3/00; capacitors having potential barriers H01L 29/00)

NOTE

In this subclass, group H01G 11/00 takes precedence over groups H01G 4/00 and H01G 9/00.

WARNING

In this subclass non-limiting references (in the sense of paragraph 39 of the Guide to the IPC) may still be displayed in the scheme.

2/00	Details of capacitors not covered by a single one of groups H01G 4/00-H01G 11/00	4/10 Metal-oxide dielectrics {(<u>H01G 4/085</u> takes precedence)}
2/02	• Mountings	4/105 {Glass dielectric}
2/04	specially adapted for mounting on a chassis	4/12 Ceramic dielectrics {(H01G 4/085 takes
2/06	specially adapted for mounting on a printed-	precedence)}
	circuit support	4/1209 (characterised by the ceramic dielectric
2/065	• • { for surface mounting, e.g. chip capacitors }	material (<u>H01G 4/1272</u> , <u>H01G 4/1281</u>
2/08	 Cooling arrangements; Heating arrangements; 	take precedence)}
	Ventilating arrangements	4/1218 {based on titanium oxides or titanates
2/10	 Housing; Encapsulation 	(<u>H01G 4/1245</u> takes precedence)}
2/103	• • {Sealings, e.g. for lead-in wires; Covers}	4/1227 {based on alkaline earth titanates}
2/106	• • {Fixing the capacitor in a housing}	4/1236 {based on zirconium oxides or
2/12	 Protection against corrosion (<u>H01G 2/10</u> takes precedence) 	zirconates (<u>H01G 4/1263</u> takes precedence)}
2/14	Protection against electric or thermal overload (by	4/1245 {containing also titanates}
	cooling <u>H01G 2/08</u>)	4/1254 {based on niobium or tungsteen,
2/16	• • with fusing elements	tantalum oxides or niobates,
2/18	with breakable contacts	tantalates}
2/20	 Arrangements for preventing discharge from edges of electrodes 	4/1263 {containing also zirconium oxides or zirconates}
2/22	Electrostatic or magnetic shielding	4/1272 {Semiconductive ceramic capacitors}
2/24	Distinguishing marks, e.g. colour coding	4/1281 {with grain boundary layer}
		4/129 {containing a glassy phase, e.g. glass
4/00	Fixed capacitors; Processes of their manufacture	ceramic}
	(electrolytic capacitors <u>H01G 9/00</u>)	4/14 Organic dielectrics
4/002	. Details	4/145 (vapour deposited)
4/005	Electrodes	4/16 of fibrous material, e.g. paper
4/008	Selection of materials	4/18 of synthetic material, e.g. derivatives of
4/0085	• • • {Fried electrodes}	cellulose (<u>H01G 4/16</u> takes precedence)
4/01	Form of self-supporting electrodes	4/183 {Derivatives of cellulose (<u>H01G 4/145</u>
4/012	Form of non-self-supporting electrodes	takes precedence)}
4/015	Special provisions for self-healing	4/186 {halogenated (<u>H01G 4/145</u> takes
4/018	Dielectrics	precedence)}
4/02	Gas or vapour dielectrics	4/20 using combinations of dielectrics from more
4/04	Liquid dielectrics	than one of groups <u>H01G 4/02</u> - <u>H01G 4/06</u>
4/06	Solid dielectrics	(H01G 4/12 takes precedence) (Eibroug material or synthetic material)
4/08	Inorganic dielectrics	4/203 {Fibrous material or synthetic material}
4/085	· · · · {Vapour deposited}	4/206 {inorganic and synthetic material}
		4/22 impregnated

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4/221	• • • • {characterised by the composition of the	5/08	becoming active in succession
	impregnant}	5/10	due to rotation of helical electrodes
4/222	{halogenated}	5/12	due to rotation of part-cylindrical, conical, or
4/224	Housing; Encapsulation	E /1.4	spherical electrodes
4/228	. Terminals	5/14	due to longitudinal movement of electrodes
4/232	• • • electrically connecting two or more layers of a	5/145	• • { with profiled electrodes }
4/2325	stacked or rolled capacitor {characterised by the material of the	5/16	. using variation of distance between electrodes
4/2323	terminals}	5/18	• due to change in inclination, e.g. by flexing, by spiral wrapping
4/236	leading through the housing, i.e. lead-through	5/38	 Multiple capacitors, e.g. ganged
4/242	the capacitive element surrounding the terminal	5/40	· Structural combinations of variable capacitors with
4/245	Tabs between the layers of a rolled electrode		other electric elements not covered by this subclass,
4/248	• • • the terminals embracing or surrounding the capacitive element, e.g. caps (<u>H01G 4/252</u>		the structure mainly consisting of a capacitor, e.g. RC combinations
	takes precedence)	7/00	Capacitors in which the capacitance is varied
4/252	element (<u>H01G 4/232</u> takes precedence)		by non-mechanical means; Processes of their manufacture
4/255	• • Means for correcting the capacitance value	7/02	• Electrets, i.e. having a permanently-polarised
4/258	Temperature compensation means	1102	dielectric
4/26	Folded capacitors	7/021	• • {having an organic dielectric}
4/28	Tubular capacitors	7/021	{of macromolecular compounds}
4/30	• Stacked capacitors (<u>H01G 4/33</u> takes precedence)	7/025	. {or macromolecular compounds}. {having an inorganic dielectric}
4/302	• • {obtained by injection of metal in cavities formed	7/026	{ with ceramic dielectric }
	in a ceramic body}	7/028	. { with ceramic dielectric }. { having a heterogeneous dielectric }
4/304	 {obtained from a another capacitor} 	7/04	 having a heterogeneous dielectric) having a dielectric selected for the variation of its
4/306	• • {made by thin film techniques}	7704	permittivity with applied temperature
4/308	• • {made by transfer techniques}	7/06	 having a dielectric selected for the variation of its
4/32	Wound capacitors	7700	permittivity with applied voltage, i.e. ferroelectric
4/33	• Thin- or thick-film capacitors {(thin- or thick-		capacitors (electrets H01G 7/02)
	film circuits H01L 27/00; capacitors without a		•
	potential-jump or surface barrier specially adapted	9/00	Electrolytic capacitors, rectifiers, detectors,
	for integrated circuits, details thereof, multistep		switching devices, light-sensitive or temperature-
	manufacturing processes therefor <u>H01L 28/40</u>)}	0.4000	sensitive devices; Processes of their manufacture
4/35	 Feed-through capacitors or anti-noise capacitors 	9/0003	• {Protection against electric or thermal overload;
4/38	 Multiple capacitors, i.e. structural combinations of fixed capacitors 		cooling arrangements; means for avoiding the formation of cathode films (<u>H01G 9/12</u> takes
4/385	• • {Single unit multiple capacitors, e.g. dual	0/0000	precedence)}
	capacitor in one coil}	9/0029	• {Processes of manufacture}
4/40	 Structural combinations of fixed capacitors with 	9/0032	• • {formation of the dielectric layer}
	other electric elements, the structure mainly	9/0036	• • {Formation of the solid electrolyte layer}
	consisting of a capacitor, e.g. RC combinations	9/004	. Details
5/00	Capacitors in which the capacitance is varied	9/008	Terminals
5/00	by mechanical means, e.g. by turning a shaft;	9/012	specially adapted for solid capacitors
	Processes of their manufacture	9/02	Diaphragms; Separators
5/01	• Details	9/022	Electrolytes; Absorbents
5/011	Electrodes	9/025	• • • Solid electrolytes (<u>H01G 11/54</u> takes
5/012	at least one of the electrodes being a		precedence)
	displaceable liquid or powder	9/028	• • • Organic semiconducting electrolytes, e.g. TCNQ
5/013 5/0132	. Dielectrics	9/032	Inorganic semiconducting electrolytes, e.g.
5/0132 5/0134	 {Liquid dielectrics} {Solid dielectrics}		MnO_2
5/0134	 {Sond delectrics} {with movable electrodes}	9/035	Liquid electrolytes, e.g. impregnating materials
			(<u>H01G 11/54</u> takes precedence)
5/0138	{ with movable dielectrics}	9/04	• • Electrodes {or formation of dielectric layers
5/014 5/015	. Housing; Encapsulation		thereon}
5/015	. Current collectors	9/042	• • • characterised by the material (<u>H01G 11/22</u>
5/017	Temperature compensation		takes precedence)
5/019	Means for correcting the capacitance characteristics	9/0425	{specially adapted for cathode}
2005/02		9/045	based on aluminium
5/04	{having air, gas, or vacuum as the dielectric}using variation of effective area of electrode	9/048	characterised by their structure (<u>H01G 11/22</u>
5/04 5/06	 using variation of effective area of electrode due to rotation of flat or substantially flat 		takes precedence)
5/00	electrodes		

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electrodes

2009/05	• • • {consisting of tantalum, niobium, or sintered	9/2081	• • {Serial interconnection of cells}
2007/03	material; Combinations of such electrodes	9/2086	{Photoelectrochemical cells in the form of a
	with solid semiconductive electrolytes, e.g.	<i>3</i> ,2000	fiber}
	manganese dioxide}	9/209	• • {Light trapping arrangements}
9/052	Sintered electrodes	9/2095	{comprising a flexible sustrate}
9/0525	• • • • {Powder therefor}	9/21	Temperature-sensitive devices
9/055	Etched foil electrodes	9/22	. Devices using combined reduction and oxidation,
9/06	Mounting in containers		e.g. redox arrangement or solion
9/07	Dielectric layers	9/26	Structural combinations of electrolytic capacitors,
9/08	Housing; Encapsulation		rectifiers, detectors, switching devices, light-
9/10	Sealing, e.g. of lead-in wires		sensitive or temperature-sensitive devices with each
9/12	Vents or other means allowing expansion		other
9/14	Structural combinations {or circuits} for	9/28	 Structural combinations of electrolytic capacitors,
	modifying, or compensating for, electric		rectifiers, detectors, switching devices with other
	characteristics of electrolytic capacitors		electric components not covered by this subclass
9/145	 Liquid electrolytic capacitors (<u>H01G 11/00</u> takes 	11/00	Hybrid capacitors, i.e. capacitors having different
	precedence)		positive and negative electrodes; Electric double-
9/15	• Solid electrolytic capacitors (<u>H01G 11/00</u> takes		layer [EDL] capacitors; Processes for the
	precedence)		manufacture thereof or of parts thereof
9/151	• • {with wound foil electrodes}		NOTE
9/153	• • {Skin fibre}		
9/16	 specially for use as rectifiers or detectors 		Group H01G 11/02 takes precedence over groups
	(H01G 9/22 takes precedence)		<u>H01G 11/04</u> - <u>H01G 11/14</u>
9/18	• Self-interrupters	11/02	. using combined reduction-oxidation reactions, e.g.
9/20	Light-sensitive devices		redox arrangement or solion
9/2004	• • {characterised by the electrolyte, e.g. comprising	11/04	Hybrid capacitors
0./2000	an organic electrolyte}	11/06	• • with one of the electrodes allowing ions to be
9/2009	• • {Solid electrolytes}		reversibly doped thereinto, e.g. lithium ion
9/2013	• • • {the electrolyte comprising ionic liquids, e.g.		capacitors [LIC]
0/2010	alkyl imidazolium iodide}	11/08	 Structural combinations, e.g. assembly or
9/2018	• • • (characterised by the ionic charge transport		connection, of hybrid or EDL capacitors with other
9/2022	species, e.g. redox shuttles}		electric components, at least one hybrid or EDL
9/2022	. {characterized by he counter electrode}. {comprising an oxide semiconductor electrode}		capacitor being the main component
9/2027	 Comprising an oxide semiconductor electrode? Comprising titanium oxide, e.g. TiO₂ 	11/10	• Multiple hybrid or EDL capacitors, e.g. arrays
9/2031	(H01G 9/2036 takes precedence)		or modules (housings, cases, encapsulations or
9/2036	• • • {comprising mixed oxides, e.g. ZnO covered	11/10	mountings thereof H01G 11/78)
7/2030	TiO ₂ particles}	11/12	Stacked hybrid or EDL capacitors
9/204	• • • {comprising zinc oxides, e.g. ZnO	11/14	 Arrangements or processes for adjusting or protecting hybrid or EDL capacitors (emergency
<i>>,</i> = 0 .	(H01G 9/2036 takes precedence)		protecting hybrid of EDE capacitors (emergency protective circuit arrangements specially adapted for
9/2045	• • {comprising a semiconductor electrode		capacitors, and effecting automatic switching in the
	comprising elements of the fourth group of the		event of an undesired change from normal working
	Periodic System (C, Si, Ge, Sn, Pb) with or		conditions <u>H02H 7/16</u> ; emergency protective circuit
	without impurities, e.g. doping materials}		arrangements for limiting excess current or voltages
9/205	 {comprising a semiconductor electrode 		without disconnection <u>H02H 9/00</u>)
	comprising AIII-BV compounds with or without	11/16	 against electric overloads, e.g. including fuses
	impurities, e.g. doping materials}	11/18	against thermal overloads, e.g. heating, cooling or
9/2054	• • {comprising a semiconductor electrode		ventilating
	comprising AII-BVI compounds, e.g. CdTe,	11/20	Reformation or processes for removal of
	CdSe, ZnTe, ZnSe, with or without impurities,		impurities, e.g. scavenging
	e.g. doping materials (<u>H01G 9/2027</u> takes precedence)}	11/22	• Electrodes
9/2059	• • {comprising an organic dye as the active light	11/24	characterised by structural features of the
9/2039	absorbing material, e.g. adsorbed on an electrode		materials making up or comprised in the
	or dissolved in solution}		electrodes, e.g. form, surface area or porosity;
9/2063	• • • {comprising a mixture of two or more dyes}		characterised by the structural features of powders or particles used therefor
9/2068	• • Panels or arrays of photoelectrochemical	11/26	• characterised by their structure, e.g. multi-
2.2000	cells, e.g. photovoltaic modules based on	11/20	layered, porosity or surface features
	photoelectrochemical cells}	11/28	arranged or disposed on a current collector;
9/2072	• • {comprising two or more photoelectrodes	11/20	Layers or phases between electrodes and
	sensible to different parts of the solar spectrum,		current collectors, e.g. adhesives
	e.g. tandem cells}	11/30	• • characterised by their material
9/2077	• • • {Sealing arrangements, e.g. to prevent the	11/32	Carbon-based
	leakage of the electrolyte}		

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H01G

11/34	characterised by carbonisation or activation of carbon
11/36	Nanostructures, e.g. nanofibres, nanotubes or
11/38	fullerenes Carbon pastes or blends; Binders or additives
11/40	therein
11/40	Fibres
11/42	• • • Powders or particles, e.g. composition thereof
11/44	Raw materials therefor, e.g. resins or coal
11/46	Metal oxides
11/48	Conductive polymers
11/50	specially adapted for lithium-ion capacitors, e.g. for lithium-doping or for intercalation
11/52	• Separators
11/54	• Electrolytes
11/56	• • Solid electrolytes, e.g. gels; Additives therein
11/58	Liquid electrolytes
11/60	characterised by the solvent
11/62	• • characterised by the solute, e.g. salts, anions or cations therein
11/64	characterised by additives
11/66	Current collectors
11/68	characterised by their material
11/70	 characterised by their structure
11/72	specially adapted for integration in multiple or stacked hybrid or EDL capacitors
11/74	. Terminals, e.g. extensions of current collectors
11/76	specially adapted for integration in multiple or stacked hybrid or EDL capacitors
11/78	. Cases; Housings; Encapsulations; Mountings
11/80	Gaskets; Sealings
11/82	Fixing or assembling a capacitive element in a housing, e.g. mounting electrodes, current collectors or terminals in containers or encapsulations
11/84	Processes for the manufacture of hybrid or EDL capacitors, or components thereof
11/86	specially adapted for electrodes (carbonisation
	or activation of carbon for the manufacture of electrodes $\underline{H01G\ 11/34}$)
13/00	Apparatus specially adapted for manufacturing
	capacitors; Processes specially adapted for manufacturing capacitors not provided for in groups H01G 4/00 - H01G 11/00
13/003	• {Apparatus or processes for encapsulating capacitors}
13/006	• {Apparatus or processes for applying terminals}
13/02	Machines for winding capacitors
13/04	• Drying; Impregnating
13/06	• with provision for removing metal surfaces
4.5.00	
15/00	Structural combinations of capacitors or other devices covered by at least two different main groups of this subclass with each other (involving at least one hybrid or electric double-layer [EDL] capacitor as the main component H01G 11/08)
17/00	Structural combinations of capacitors or other devices covered by at least two different main groups of this subclass with other electric elements, not covered by this subclass, e.g. RC combinations

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